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FFSP3065B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 144 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuit

ABSOLUTE MAXIMUM RATINGS

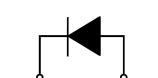
(T_C = 25°C, Unless otherwise specified)

Symbol	Para	Value	Unit				
V _{RRM}	Peak Repetitive Rev	650	V				
E _{AS}	Single Pulse Avalan	144	mJ				
	Continuous Rectified @ $T_C < 135^{\circ}C$	30					
I _{F, Max}	Non-Repetitive Peak Forward	$T_C = 25^{\circ}C$, 10 µs	1100	Α			
	Surge Current	$T_{C} = 150^{\circ}C, 10 \ \mu s$	1000				
I _{F, SM}	Non-Repetitive Forward Surge Current	Half–Sine Pulse, t _p = 8.3 ms	110	A			
P _{tot}	Power Dissipation	$T_C = 25^{\circ}C$	197	W			
		$T_C = 150^{\circ}C$	33				
T _J , T _{STG}	Operating and Stora Range	–55 to +175	°C				

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

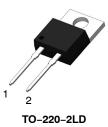
1. E_{AS} of 144 mJ is based on starting T_J = 25°C, L = 0.5 mH, I_{AS} = 24 A, V = 50 V.

DATA SHEET www.onsemi.com



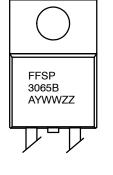
ELECTRICAL CONNECTION

1. Cathode 2. Anode



CASE 340BB

MARKING DIAGRAM



FFSP3065B	= Specific Device Code
Α	= Assembly Location
Y	= Year
WW	= Work Week
ZZ	= Assembly Lot Code
	,

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

FFSP3065B

THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.76	°C/W

ELECTRICAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _F	Forward Voltage	$I_{F} = 30 \text{ A}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	1.38	1.7	V
		$I_{F} = 30 \text{ A}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	1.6	2.0	
		$I_F = 30 \text{ A}, \text{T}_C = 175^{\circ}\text{C}$	-	1.72	2.4	
I _R	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	0.5	40	μA
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 125^{\circ}\text{C}$	-	1.0	80	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	2.0	160	
Q_{C}	Total Capacitive Charge	V = 400 V	-	74	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	1280	-	pF
		V _R = 200 V, f = 100 kHz	-	139	-	1
		V _R = 400 V, f = 100 kHz	-	108	_	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP3065B	FFSP3065B	TO-220-2L	Tube	N/A	N/A	50 Units

FFSP3065B

TYPICAL CHARACTERISTICS $T_J = 25^{\circ}C$ UNLESS OTHERWISE NOTED

250

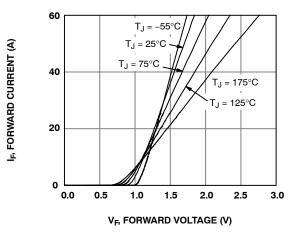


Figure 1. Forward Characteristics

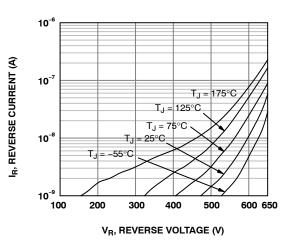


Figure 2. Reverse Characteristics

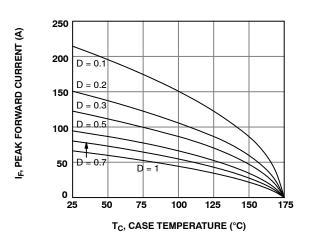
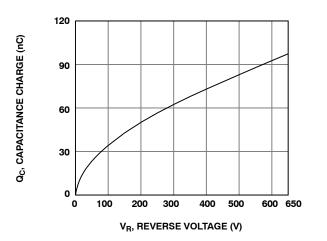


Figure 3. Current Derating





 $\begin{array}{c} \textbf{W} \\ \textbf{NOLTERS } \\ \textbf{UL} \\ \textbf{$

Figure 4. Power Dissipation

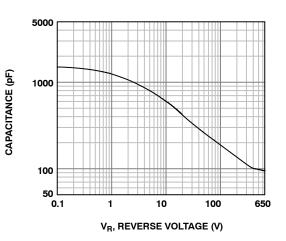
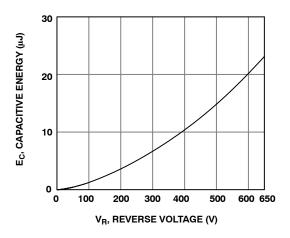
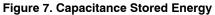


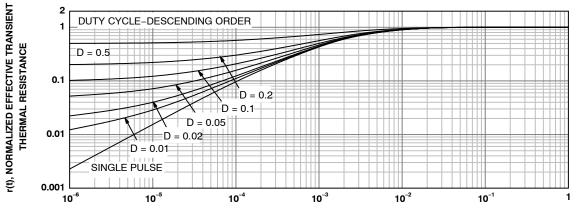
Figure 6. Capacitance vs. Reverse Voltage

FFSP3065B

TYPICAL CHARACTERISTICS $T_J = 25^{\circ}C$ UNLESS OTHERWISE NOTED (CONTINUED)

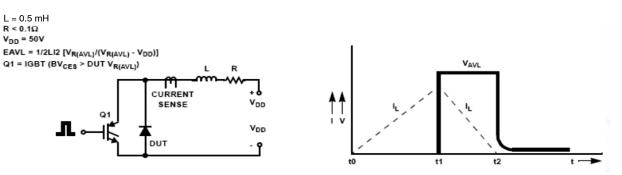






t, RECTANGULAR PULSE DURATION (sec)

Figure 8. Junction-to-Case Transient Thermal Response Curve



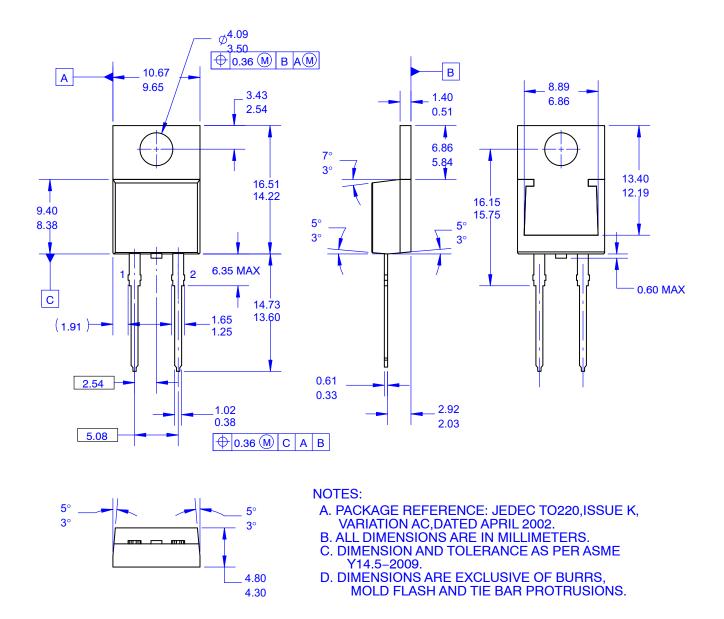
TEST CIRCUIT AND WAVEFORMS

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform



TO-220-2LD CASE 340BB ISSUE O

DATE 31 AUG 2016



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